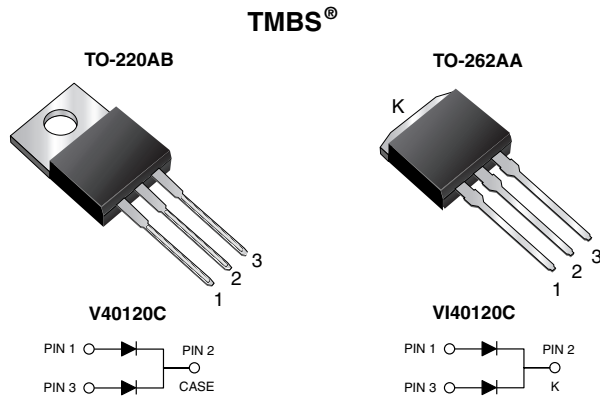


Dual High Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.43 \text{ V}$ at $I_F = 5 \text{ A}$


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
V_{RRM}	120 V
I_{FSM}	250 A
V_F at $I_F = 20 \text{ A}$	0.63 V
T_J max.	150 °C
Package	TO-220AB, TO-262AA
Diode variation	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V40120C	VI40120C	UNIT
Max. repetitive peak reverse voltage	V_{RRM}	120		V
Max. average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	40	A
		per diode	20	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	250		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150		°C



ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.50	-	V
	I _F = 10 A			0.60	-	
	I _F = 20 A			0.78	0.88	
	I _F = 5 A	T _A = 125 °C		0.43	-	
	I _F = 10 A			0.53	-	
	I _F = 20 A			0.63	0.71	
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	19	-	μA
		T _A = 125 °C		10	-	mA
	V _R = 120 V	T _A = 25 °C		-	500	μA
		T _A = 125 °C		22	45	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	V40120C	VI40120C	UNIT
Typical thermal resistance per diode	R _{θJC}	1.8		°C/W

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V40120C-M3/4W	1.88	4W	50/tube	Tube
TO-262AA	VI40120C-M3/4W	1.45	4W	50/tube	Tube
TO-220AB	V40120CHM3/4W ⁽¹⁾	1.88	4W	50/tube	Tube
TO-262AA	VI40120CHM3/4W ⁽¹⁾	1.45	4W	50/tube	Tube

Note

- (1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

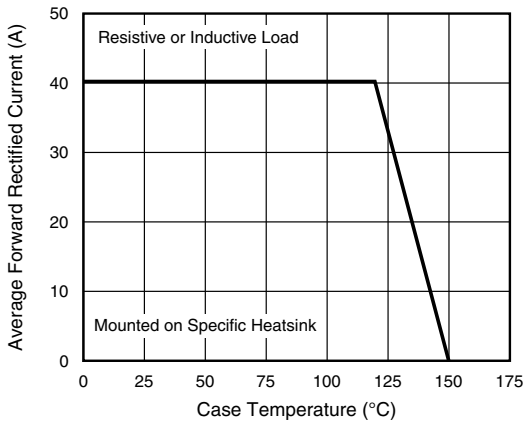


Fig. 1 - Maximum Forward Current Derating Curve

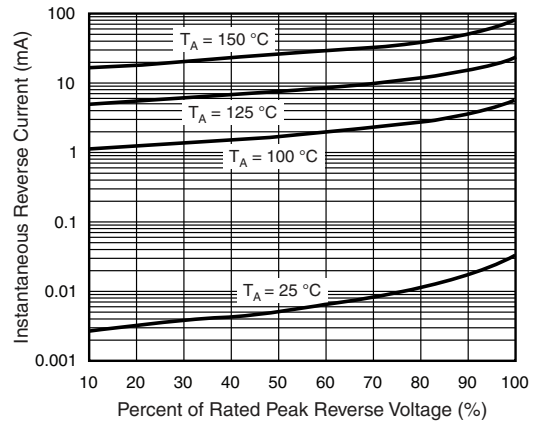


Fig. 4 - Typical Reverse Characteristics Per Diode

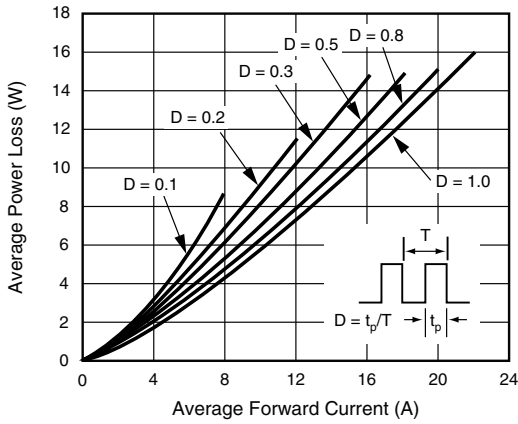


Fig. 2 - Forward Power Loss Characteristics Per Diode

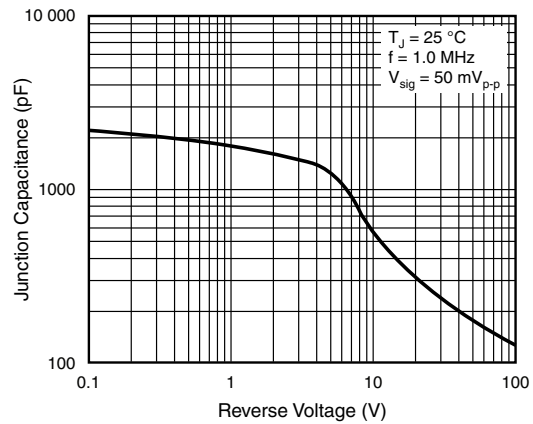


Fig. 5 - Typical Junction Capacitance Per Diode

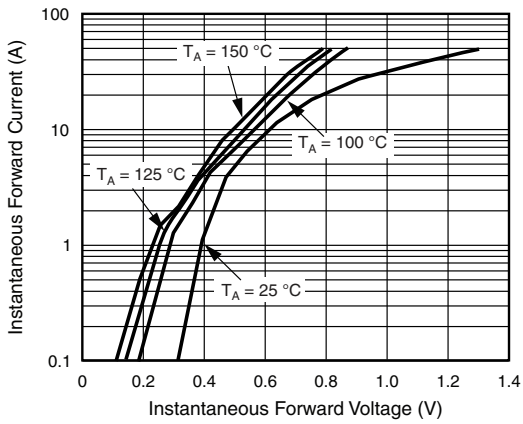


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

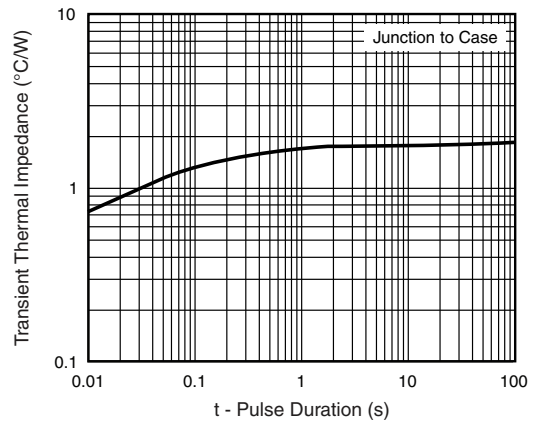
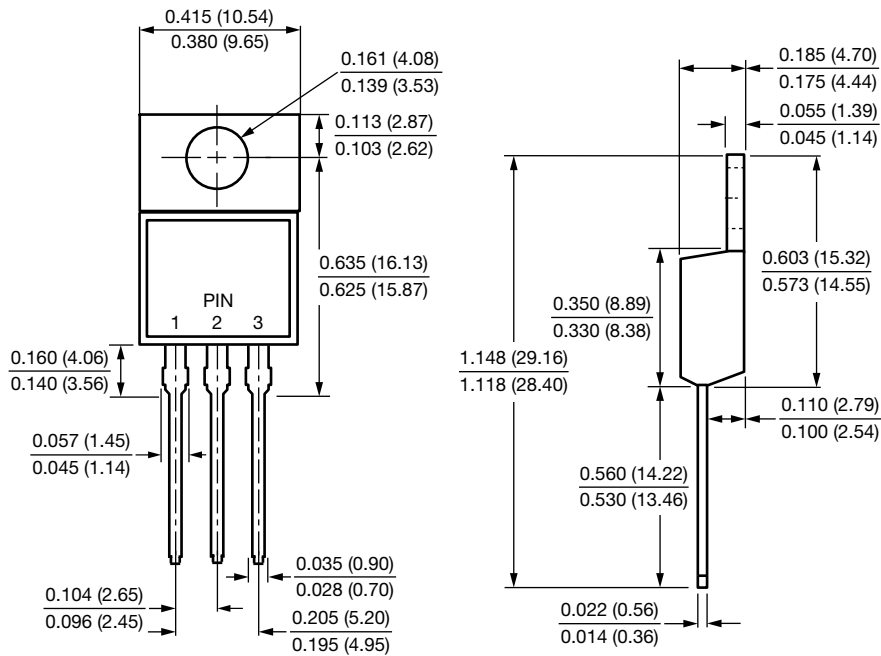


Fig. 6 - Typical Transient Thermal Impedance Per Diode

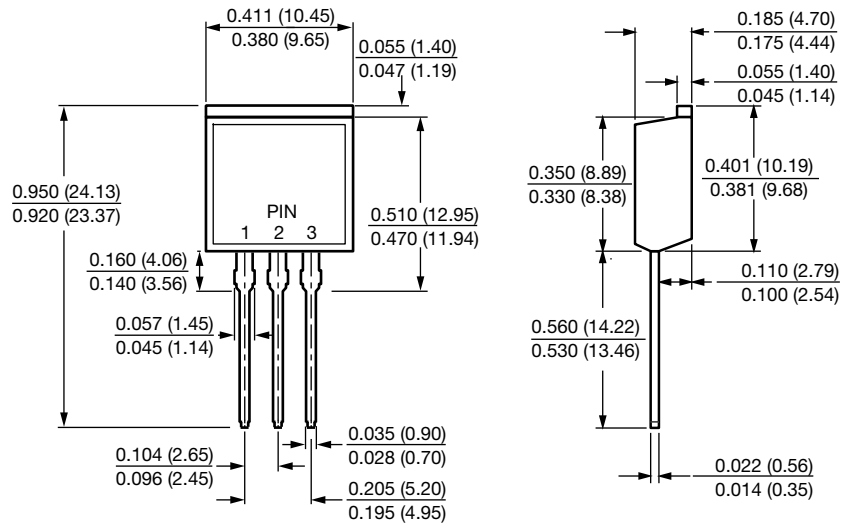


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA





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